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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

he application of

Attn: APPLICATION BRANCH

Toshiyuki TAKIZAWA

Docket No. 2004 0347A

Serial No. 10/790,864

Filed March 3, 2004

P-TYPE SEMICONDUCTOR AND SEMICONDUCTOR HETERO MATERIAL AND MANUFACTURING METHODS THEREOF

INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Pursuant to the provisions of 37 C.F.R. 1.56, 1.97 and 1.98, Applicants request consideration of the references listed on the attached Form PTO-1449. A legible copy of each reference listed on the Form PTO-1449 is enclosed, except a copy is not provided for each U.S. Patent and U.S. Patent application publication (for U.S. National applications filed after June 30, 2003 and International applications that have entered U.S. National Stage after June 30, 2003).

1a. [X] This Information Disclosure Statement is submitted:

within three months of the filing date (or of entry into the National Stage) of the aboveentitled application, or

before the mailing of a first Office Action on the merits or the mailing of a first Office Action after the filing of an RCE,

and thus no certification and/or fee is required.

1b. [] This Information Disclosure Statement is submitted

after the events of above paragraph 1a and prior to the mailing date of a final Office Action or a Notice of Allowance or an action which otherwise closes prosecution in the application, and thus:

- (1) [] the certification of paragraph 2 below is provided, or
- (2) [] the fee of \$180.00 specified in 37 CFR 1.17(p) is enclosed.
- 1c. [] This Information Disclosure Statement is submitted:

after the mailing date of a final Office Action or Notice of Allowance or action which otherwise closes prosecution in the application, and prior to payment of the issue fee, and thus:

the certification of paragraph 2 below is provided, and

the fee of \$180.00 specified in 37 CFR 1.17(p) is enclosed.

- 2. It is hereby certified
 - a. [] that each item of information contained in this Information Disclosure Statement was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the Statement, or
 - b. [] that no item of information contained in the Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application and, to the knowledge of the person signing the certification after making reasonable inquiry, was known to any individual designated in §1.56(c) more than three months prior to the filing of the Statement.
- 3. [] Consideration of the following list of additional information (including any copending or abandoned U.S. application, prior uses and/or sales, etc.) is requested.
- 4. For each non-English language reference listed on the attached form PTO-1449, reference is made to:
 - a. [] a full or partial English language translation submitted herewith,

- b. [] a foreign patent office search report (in the English language) submitted herewith,
- c. [X] the concise explanation contained in the specification of the present application at pages 2-3,
- d. [X] the concise explanation set forth in the attached English language abstracts,
- e. [] the concise explanation set forth below or on a separate sheet attached to the reference:
- 5. [] A foreign patent office search report citing one or more of the references is enclosed.

Respectfully submitted,

Toshiyuki TAKIZAWA

By

Michael S. Huppert Registration No. 40,268 Attorney for Applicants

MSH/kjf Washington, D.C. 20006-1021 Telephone (202) 721-8200 Facsimile (202) 721-8250 May 21, 2004

Sheet 1 of 1										
FORM PTO 1449 (modified)				ATTY DOCKET NO. SERIAL I						
U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE				2004_0347A 10/790,864 APPLICANT Techinglis TAKIZANAA						
LIST OF REFERENCES CITED BY APPLICANT(S) (Use several sheets if necessary)				Toshiyuki TAKIZAWA FILING DATE GROUP						
Date Submitted to PTO: May 21, 2004				March 3, 2004				GROUP		
U.S. PATENT DOCUMENTS										
O EXAMPLE TO INITIAL TO		DOCUMENT NUMBER	DATE	NAME CLASS		SUBCLASS	FILING DATE IF APPROPRIATE			
MAY 2 1 2004	AA	2002/0034861	3/2002	lwa	ita et al.	ļ				
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FOREIGN PATENT DOCUMENTS										
		DOCUMENT NUMBER	DATE	co	COUNTRY CLASS			SUBCLASS	TRANSLATION YES NO	
	AJ	7-249820	9/1995		JP		·		Abstract	
	AK	2002-289918	10/2002		JP		<u>.</u>		Abstract	
	AL	2002-50229	2/2002		JP				Abstract	
:	АМ	2002-353144	12/2002		JP				Abstract	
	AN	2002-93821	3/2002		JP				Abstract	
OTHER DOCUMENT(S) (Including Author, Title, Date, Pertinent Pages, Etc.)										
·	AO									
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EXAMINER					DATE CONSIDERED					